NSN 5961-01-645-9870

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-645-9870

| view Offinite at https://aerobasegroup.com/hsi/ |
|---|
| Overall Length: |
| Between 4.00 millimeters and 4.60 millimeters |
| Overall Height: |
| Between 2.29 millimeters and 2.92 millimeters |
| Overall Width: |
| Between 1.96 millimeters and 2.40 millimeters |
| End Application: |
| Landing gear systems/components |
| Mounting Method: |
| Terminal |
| Voltage Rating In Volts Per Characteristic: |
| 400.0 repetitive peak reverse voltage |
| Current Rating Per Characteristic: |
| 1.0 amperes forward current, dc |
| Special Features: |
| Temp range -65c to +150c |
| Terminal Type And Quantity: |
| 2 printed circuit |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |

Fiig: A110a0